

ZXTN5551G 160V, SOT223, NPN high voltage transistor

Summary

BV_{CEO} > 160V

 $BV_{EBO} > 6V$

 $I_{C(cont)} = 600 mA$

 $P_D = 2W$

Complementary part number ZXTP5401G

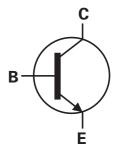


Description

A high voltage NPN transistor in a high power dissipation surface mount package

Features

- 160V rating
- SOT223 package

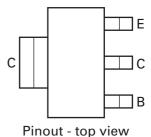


Applications

• High voltage amplification

Ordering information

Device	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTN5551GTA	7	12	1000
ZXTN5551GTC	13	12	4000



Device marking

ZXTN 5551

Absolute maximum ratings

Parameter	Symbol	Limit	Unit
Collector-base voltage	V _{CBO}	180	V
Collector-emitter voltage	V _{CEO}	160	V
Emitter-base voltage	V _{EBO}	6	V
Continuous collector current ^(a)	I _C	600	mA
Power dissipation at $T_A = 25^{\circ}C^{(a)}$	P _D	2	W
Linear derating factor		16	mW/°C
Operating and storage temperature range	T _j , T _{stg}	-55 to 150	°C

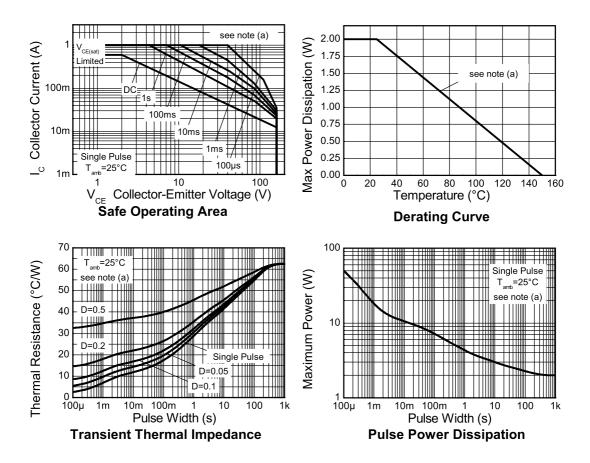
Thermal resistance

Parameter	Symbol	Value	Unit
Junction to ambient ^(a)	$R_{\Theta JA}$	62.5	°C/W

NOTES:

(a) For a device surface mounted on 50mm x 50mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.

Characteristics

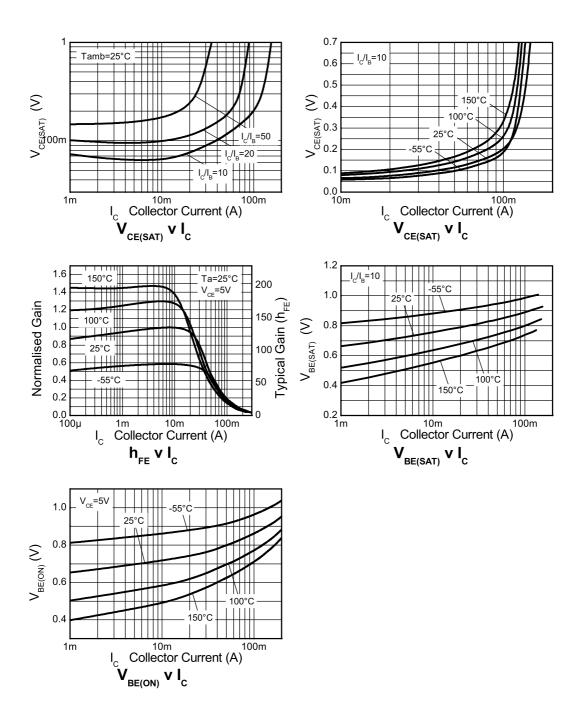


Electrical characteristics (at $T_{amb} = 25$ °C unless otherwise stated).

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	BV _{CBO}	180	270		V	I _C = 100μA
Collector-emitter breakdown voltage (base open)	BV _{CEO}	160	200		V	I _C = 1mA ^(*)
Emitter-base breakdown voltage	BV _{EBO}	6	7.85		V	I _E = 10μA
Collector cut-off current	I _{CBO}		<1	50	nA	V _{CB} = 120V
				50	μΑ	$V_{CB} = 120V, T_{amb} = 100^{\circ}C$
Collector-emitter	V _{CE(Sat)}		65	150	mV	I _C = 10mA, I _B = 1mA ^(*)
saturation voltage			115	200	mV	$I_C = 50 \text{mA}, I_B = 5 \text{mA}^{(*)}$
Base-emitter saturation	V _{BE(Sat)}		760	1000	mV	I _C = 10mA, I _B = 1mA ^(*)
voltage			840	1200	mV	$I_C = 50 \text{mA}, I_B = 5 \text{mA}^{(*)}$
Static forward current	h _{FE}	80	135			I _C = 1mA, V _{CE} = 5V ^(*)
transfer ratio		80	140	250		$I_C = 10 \text{mA}, V_{CE} = 5 V^{(*)}$
		30	65			$I_C = 50 \text{mA}, V_{CE} = 5 V^{(*)}$
Transition frequency	f _T		130		MHz	I _C = 10mA, V _{CE} = 10V f = 100MHz
Output capacitance	C _{OBO}			6	pF	V _{CB} = 10V, f = 1MHz ^(*)
Small signal	h _{FE}	50		260		$I_C = 10 \text{mA}, V_{CE} = 10 \text{V},$ f=1kHz ^(†)
Delay time	t _(d)		95		ns	$V_{CC} = 10V. I_C = 10mA,$
Rise time	t _(r)		64		ns	$I_{B1} = I_{B2} = 1mA$
Storage time	t _(s)		1256		ns	
Fall time	t _(f)		140		ns	

^(*) Measured under pulsed conditions. Pulse width ${\le}300\mu s;$ duty cycle ${\le}2\%.$ (†) Periodic sample test only.

Typical Characteristics

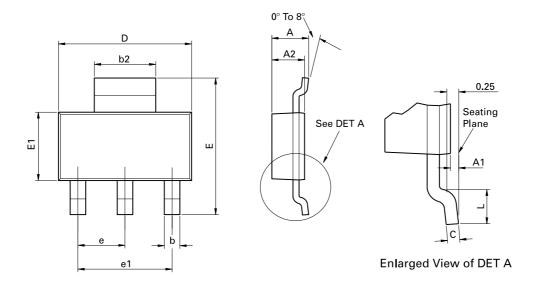




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Package outline - SOT223



Conforms to JEDEC TO-261 AA Issue B

Dim.	Millin	neters	Inc	hes	Dim.	Millimeters		Inches	
Dilli.	Min.	Max.	Min.	Max.	Dilli.	Min.	Max.	Min.	Max.
Α	-	1.80	-	0.071	D	6.30	6.70	0.248	0.264
A1	0.02	0.10	0.0008	0.004	е	2.30	BSC	0.090	5 BSC
A2	1.55	1.65	0.0610	0.0649	e1	4.60	BSC	0.181	BSC
b	0.66	0.84	0.026	0.033	E	6.70	7.30	0.264	0.287
b2	2.90	3.10	0.114	0.122	E1	3.30	3.70	0.130	0.146
С	0.23	0.33	0.009	0.013	L	0.90	-	0.355	-

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

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